

300mA, Dual Channel Ultra-Fast CMOS LDO Regulato

General Description

The LP2201 is a dual channel, low noise, and low dropout regulator sourcing up to 300mA at each channel. The range of output voltage is from 1.2V to 3.6V from operating from 2.5V to 5.5V input.

LowPowerSemi 微源半導體

LP2201 offers 2% accuracy, extremely low dropout voltage (80mV @ 100mA), and extremely low ground current, only 25µA per LDO. The shutdown current is near zero current which is suitable for battery-power devices. Other features include current limiting, over temperature, output short circuit protection.

LP2201 is short circuit thermal folded back protected. LP2201 lowers its OTP trip point from 165°C to 110°C when output short circuit occurs (VOUT<0.4V) providing maximum safety to end users.

LP2201 can operate stably with very small ceramic output capacitors, reducing required board space and component cost. LP2201 is available in fixed output voltages in the SOT-23-6 package.

Order Information

LP2201 🗆 🗆 🗆 F: Pb-Free Package Type B6: SOT23-6 Out1/Out2 Voltage Type 18/28: 1.8V/2.8V 18/33: 1.8V/3.3V 25/28: 2.5V/2.8V 28/28: 2.8V/2.8V 28/12: 2.8V/1.2V 28/33: 2.8V/3.3V 30/30: 3.0V/3.0V 30/33: 3.0V/3.3V 33/33: 3.3V/3.3V 18/26: 1.8V/2.6V 15/28: 1.5V/2.8V

Features

- Wide Operating Voltage Ranges : 2.5V to 5.5V
- Low-Noise for RF Application
- High PSRR 65dB at 1kHz
- No Noise Bypass Capacitor Required
- Fast Response in Line/Load Transient
- TTL-Logic-Controlled Shutdown Input
- Dual LDO Outputs (250mV/300mA)
- High Output Accuracy 2%
- Ultra-low Quiescent Current 27uA
- Thermal Shutdown Protection
- Thermal Shutdown Protection
- Tiny SOT-23-6 Package
- RoHS Compliant and 100% Lead (Pb)-Free

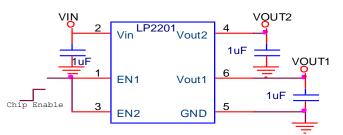
Applications

- CDMA/GSM Cellular Handsets
- ♦ Smart mobile phone
- Battery-Powered Equipment
 - DSC Sensor

∻

Wireless Card

Typical Application Circuit



Marking Information

Device	Marking	Package	Shipping
LP2201-02		SOT23-6	3K/REEL

LP2201-02

13/28: 1.3V/2.8V

www.lowpowersemi.com



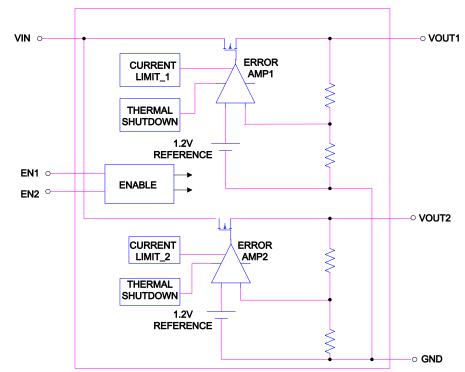
Functional Pin Description

Package Type	Pin Configurations		
	TOP VIEW		
	EN1 1 6 VOUT1		
SOT23-6	VIN 2 5 GND		
	EN2 3 4 VOUT2		
	SOT23-6		

Pin Description

Pin	Name	Description
1	EN1	Chip Enable1 (Active High)
2	VIN	Supply Input
3	EN2	Chip Enable2 (Active High)
4	VOUT2	Channel 2 Output Voltage
5	GND	Common Ground
6	VOUT1	Channel 1 Output Voltage
_		🔟 LowPowerSemi 微源半導體

Function Diagram





Absolute Maximum Ratings

\diamond	Supply Input Voltage	6V
Po	ower Dissipation, PD @ TA = 25°C	
\diamond	SOT23-6	450mW
Pa	ackage Thermal Resistance	
\diamond	SOT23-6, 0JA	250°C/W
\diamond	Lead Temperature (Soldering, 10 sec.)	260°C
\diamond	Storage Temperature Range	−65°C to 150°C
ES	SD Susceptibility	
\diamond	HBM (Human Body Mode)	2kV
\diamond	MM(Machine-Mode)	200V
Re	ecommended Operating Conditions	
\diamond	Operation Junction Temperature Range	−40°C to 125°C
\diamond	Operation Ambient Temperature Range	40°C to 85°C

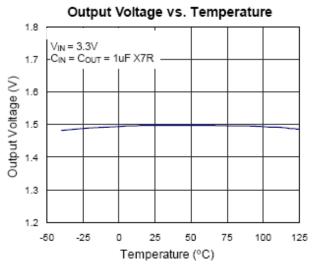
Electrical Characteristics

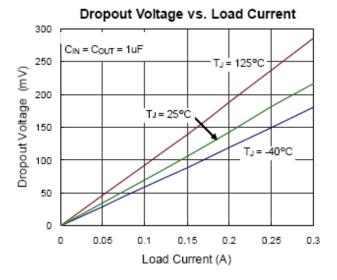
(VIN = VOUT + 1V, CIN = COUT = 1μ F, TA = 25° C, unless otherwise specified)

Pa	arameter	r h 26mi	Symbol	Test Conditions		Тур	Max	Units
Output Voltage Accuracy		Δνουτ	JOUT = 1mA	-2	lutta	+2	%	
Maximum output Current		Imax	Continuous	300	D		mA	
Cur	rent Limi	t	ILIM	RLOAD = 1Ω	360	400	700	mA
Quies	cent Curr	rent	IQ	VEN ≥ 1.2V, IOUT = 0mA		75	110	μA
Dropout Voltage		VDROP	IOUT = 30mA, VOUT > 2.8V		30	45	mV	
			IOUT = 150mA, VOUT > 2.8V		80	150	mV	
Line Regulation		ΔVLINE	VIN = (VOUT + 1V) to 5.5V, IOUT = 1mA			0.3	%	
Load Regulation		ΔLOAD	1mA < IOUT < 300mA			0.6	%	
Standby Current		ISTBY	VEN = GND, Shutdown		0.01	1	μA	
EN Inpu	t Bias Cu	ırrent	IIBSD	VEN = GND or VIN	0 100		100	nA
	Logic-Low Voltage		VIL	VIN = 3V to 5.5V, Shutdown			0.4	V
EN Threshold	Logic-High Voltage		VIH	VIN = 3V to 5.5V, Start-Up	1.2			V
Output Noise Voltage			10Hz to 100kHz, IOUT = 200mA COUT =		100		uVRM	
			1µF		100		S	
Power Sup	ply	f = 100Hz	PSRR			-75		dB
Rejection R	ate	f = 10kHz	FORR	$COUT = 1\mu F$, $IOUT = 10mA$		-65		dB
Thermal Shutdown Temperature		TSD			150		°C	

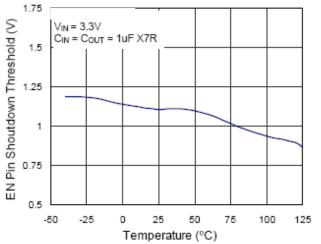


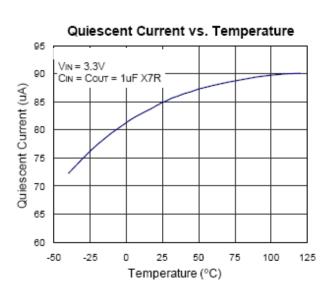
Typical Operating Characteristics



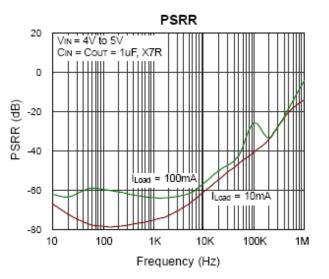




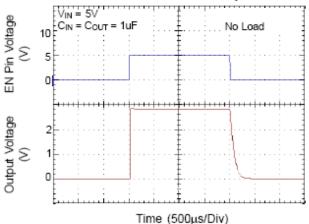




LP2201



EN Pin Shutdown Response





Applications Information

Like any low-dropout regulator, the external capacitors used with the LP2201 must be carefully selected for regulator stability and performance. Using a capacitor whose value is > 1µF on the LP2201 input and the amount of capacitance can be increased without limitation. The input capacitor must be located in a distance of no more than 0.5 inch from the input pin of the IC and returned to a clean analog ground. Any good quality ceramic or tantalum can be used for this capacitor. The capacitor with larger value and lower ESR (equivalent series resistance) provides better PSRR and line-transient response. The output capacitor must meet both requirements for minimum amount of capacitance and ESR in all LDOs application. The LP2201 is designed specifically to work with low ESR ceramic output capacitor in space-saving and performance consideration. Using a ceramic capacitor whose value is at least 1µF with ESR is > $25m\Omega$ on the LP2201 output ensures stability. The LP2201 still works well with output capacitor of other types due to the wide stable ESR range. Figure 1 shows the curves of allowable ESR range as a function of load current for various output capacitor values. Output capacitor which is of larger capacitance can reduce noise and improve the speed of load transient response, stability, and PSRR. The output capacitor should be located no more than 0.5 inch from the VOUT pin of the LP2201 and returned to a clean analog ground.

Start-up Function Enable Function

The LP2201 features an LDO regulator enable/disable function. To ensure the LDO regulator will switch on, the EN turn on control level must be greater than 1.2 volts. The LDO regulator will go into the shutdown mode when the voltage on the EN pin falls below 0.4 volts. For to protecting the system, the LP2201 have a quick-discharge function. If the enable function is not needed in a specific application, it may be tied to VIN to keep the LDO regulator in a continuously on state.

Thermal Considerations

Thermal protection limits power dissipation in LP2201. When the operation junction temperature exceeds 150°C, the OTP circuit starts the thermal shutdown function turn the pass element off. The pass element turn on again after the junction temperature cools by 25°C. For continuous operation, do not exceed absolute maximum operation junction temperature 125°C.

The power dissipation definition in device is :

 $PD = (VIN-VOUT) \times IOUT + VIN \times IQ$

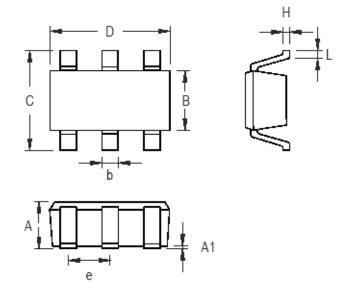
The maximum power dissipation depends on the thermal resistance of IC package, PCB layout, the rate of surroundings airflow and temperature difference between junction to ambient.

The maximum power dissipation can be calculated by following formula :

 $PD(MAX) = (TJ(MAX) - TA)/\theta JA$



Package Information



Cumhal	Dimensions	n Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
А	0.889	1.295	0.031	0.051	
A1	0.000	0.152	0.000	0.006	
В	1.397	1.803	0.055	0.071	
b	0.250	0.560	0.010	0.022	
С	2.591	2.997	0.102	0.118	
D	2.692	3.099	0.106	0.122	
е	0.838	1.041	0.033	0.041	
Н	0.080	0.254	0.003	0.010	
L	0.300	0.610	0.012	0.024	

SOT-23-6 Surface Mount Package